M.Sc.(Physics) (NEP Pattern) Semester-I NEP-233 / 01MSCPH1 - DSE Paper-I - Semiconductor Physics and Devices

P. Pages : 2 Time : Three Hours		2 ree Hours	$\begin{array}{c} & & & \\ & & & \\ & \star & 8 & 0 & 6 & 1 & \star \end{array} \qquad \qquad$	
	Notes : 1. All q 2. Draw		estions are compulsory. neat and well labelled diagrams wherever necessary	у.
		Either:		
1.	a)	What is junctic channel JFET	on field effect transistor? Explain the construction an with the help of proper diagrams.	nd working of a N 8
	b)	Explain the control the application	nstruction and working of SCR. Discuss the charact s of SCR.	eristics of SCR. State 8
			OR	
	e)	Discuss the con	nstruction and working of UJT. State its application	s. G
	f)	Explain the con	nstruction and voltage ampere characteristics of a p-	-n photo diode.
	g)	Write a note or	n Solar Cell.	4
		Either:		
2.	a)	Draw a circuit	diagram of TTL based OR and AND gate and expla	ain its working . 8
	b)	Explain the conoscillator.	nstruction of Hartley Oscillator. Obtain an expression	on for the frequency of 8
			OR	
	e)	What is the use amplifier. Also	e of coupling in amplifier? Draw a circuit diagram o explain its frequency response graph.	of RC coupled transistor 8
	f)	What is the dif Oscillators in c	ference between an amplifier and an oscillator? Expletailed.	blain the Colpitts 8
		Either:		
3.	a)	What is a EXC Adder.	LASIVE OR gate? Explain the use of XOR gate as	a Half Adder and Full 8
	b)	What is the rac	e around condition? Describe the construction and	working of JKMSFF. 8
			OR	
	e)	Explain the con	nstruction and working of JKFF.	٤
	f)	What is a mult	ivibrator? Explain the construction and working of a	astable multivibrator.

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Either:

4.	a)	What is a Magnetron? Describe the principle, construction and working of a Magnetron.			
	b)	Explain IMPATT Diode in detail. State its advantages & disadvantages.		8	
		OR			
	e)	Explain microwave transmission in detail & What are the advantages and disadvantages of Microwave transmission?		8	
	f)	Explain the construction and working of TRAPATT Diode.		8	
5.		Attempt all of the followings.			
		a)	Draw the circuit to study the characteristics of n-p-n transistor in CE mode. Explain the input and output characteristics of it.	4	
		b)	Describe the working of common source JFET Amplifier.	4	
		c)	Explain the use of OP AMP as an adder.	4	
		d)	What are Transferred Electron Devices? Give its example explain it.	4	
